

Isc N-Channel MOSFET Transistor

STP18N65M5

FEATURES

- Higher V_{DSS} rating
- · Excellent switching performance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

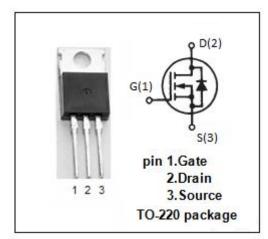


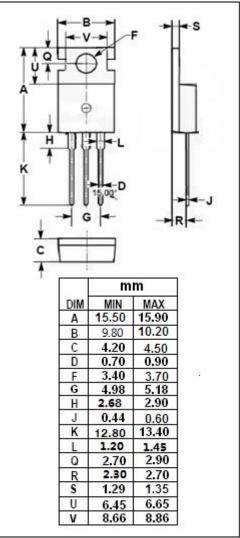
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GSS}	Gate-Source Voltage	±25	V
Ι _D	Drain Current-Continuous@T _C =25℃ T _C =100℃	15 9.4	А
Ідм	Drain Current-Single Pulsed	60	А
P _D	Total Dissipation	110	W
Tj	Operating Junction Temperature	-55~150	$^{\circ}$
T _{stg}	Storage Temperature -55~150		$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.14	°C/W





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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =±25V; I _D =0.25mA	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =7.5A			220	mΩ
Igss	Gate-Source Leakage Current	V _{GS} = ±25V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V; T _J =25°C T _J =125°C			1 100	μ A
V _{SDF}	Diode forward voltage	I _{SD} =15A, V _{GS} = 0 V			1.5	V

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